

上海大真空国際貿易有限公司

ITEM :

# CRYSTAL OSCILLATOR

TYPE :

DSA321SDN

NOMINAL FREQUENCY :

13.000MHz

SPEC No. :

1XTV13000MAA

Please acknowledge receipt of this specification by signing and returning a copy to us.

	RECEIPT
DATE	
RECEIVED	(signature) (name)

General Manufacturer of Quartz Devices



675-0194 Japan Phone (81)79-425-3141 Fax (81)79-425-1134 http://www.kds.info/index\_en.htm

A. Hishikawa C.ENG

ENG.

Takase

- 1. Device Name VC-TCXO
- 2. Model Name DSA321SDN
- 3. Nominal Frequency 13.000 MHz
- 4. Mass 0.03g max.

5. Absolute Maximum Ratings

	Item	Symbol		Rating			
1	Supply Voltage	Vcc	-0.3~+4.6			V	
2	Storage Temperature Range	T_ <sub>STG</sub>	-40~+85			°C	
6. Recommended Operating Conditions							
	Item	Symbol	min.	typ.	max.	unit	
1	Supply Voltage	V <sub>CC</sub>	+2.85	+3.0	+3.15	V	
2	Load Impedance (resistance part)	$L_{OAD}R$	9	10	11	kΩ	
	(parallel capacitance)	L <sub>OAD</sub> _C	9	10	11	pF	
3	Control Voltage Range	V <sub>CONT</sub>	+0.5	+1.5	+2.5	V	
4	Operating Temperature Range	T_ <sub>OPR</sub>	-30	-	+85	°C	

7. Electrical Characteristics

 $(T_A=-30 \sim +85^{\circ}C, L_{OAD}R/C=10k\Omega//10pF, V_{CC}=+3.0V, V_{CONT}=+1.5V, unless otherwise noted)$ 

			1		- ,		
	Itom	Conditions		Limits		unit	Notoo
	Item	Conditions	min. typ		max.	unit	Notes
1	Current Consumption		-	-	+1.5	mA	
2	Output Level		0.8	-	-	$V_{P-P}$	1
3	Symmetry	GND level (DC cut)	40/60	-	60/40	%	
4	Harmonics		-	-	-5	dBc	
5	Frequency Stability						
	1.Tolerance	After 2 times reflow Ref. to nominal frequency	-	-	±1.5	ppm	2,3
	2.vs Temperature	$T_A$ =-30~+85°C Ref. to frequency ( $T_A$ =+25°C)	-	-	±2.5	ppm	
	3.vs Supply Voltage	V <sub>CC</sub> =+3.0V±5%	-	-	±0.2	ppm	
	4.vs Load Variation	L <sub>OAD</sub> _R//C=(10kΩ//10pF)±10%	-	-	±0.2	ppm	
	5.vs Aging	T <sub>A</sub> =Room ambient	-	-	±1.0	ppm/year	
6	Start Up Time	@90% of final Vout level	-	-	2.0	ms	
7	Frequency Control 1.Control Range	V <sub>CONT</sub> =+1.5V±1.0V	±9	-	±15	ppm	4
	2.Input Resistance		500	-	-	kΩ	
8	SSB Phase Noise	Relative to f0 level offset 1kHz	-	-	-135	dBc/Hz	

Notes

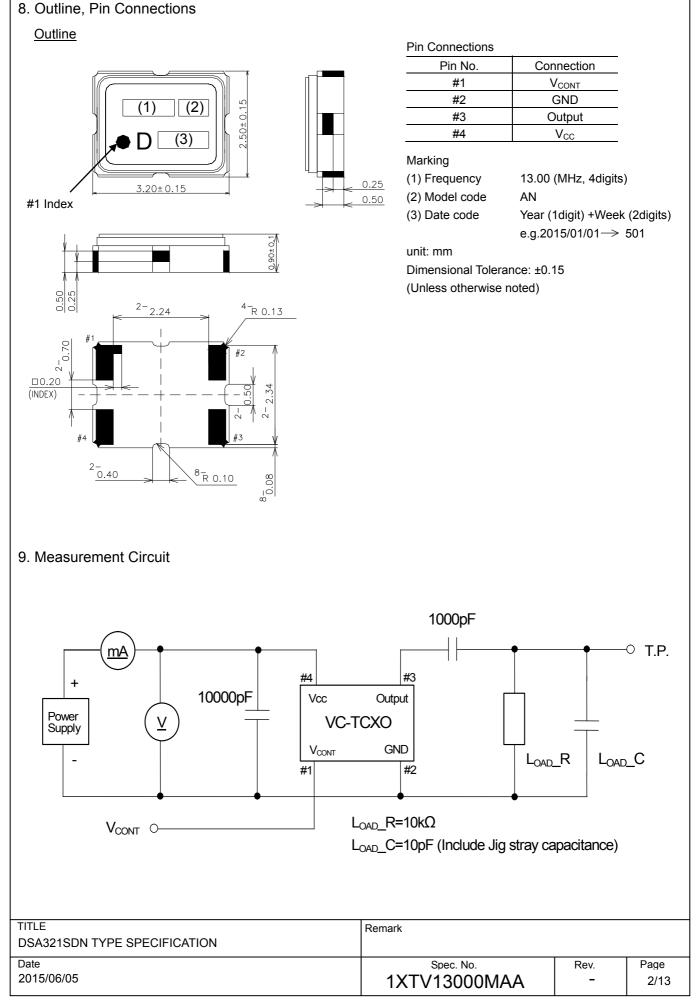
1. Clipped sine wave (DC-coupled)

2. T<sub>A</sub>=+25°C

3. Please leave after reflow in 2h or more at room ambient.

4. Positive slope (Frequency becomes high in proportion to frequency control voltage.)

TITLE	Remark		
DSA321SDN TYPE SPECIFICATION			
Date	Spec. No.	Rev.	Page
2015/06/05	1XTV13000MAA	-	1/13

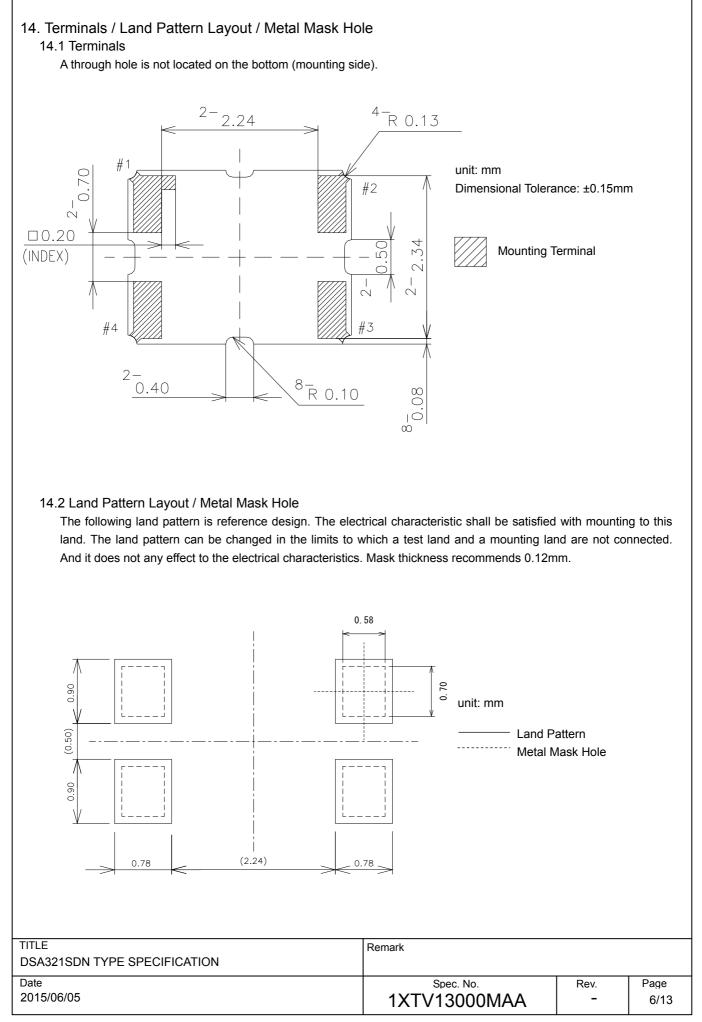


	1	I test is performed after 3times reflow (C				y net	
_	Item	Description		Req	uirements		
1	Drop	Natural drop (On concrete)					
		Mounting on the set or test fixture.(Tot	al weight 100g)				
		Height : 150cm	df/f=<±1.0pp	om			
		Direction : X,Y,Z, 6directions					
		Test cycle : 3cycles					
		Reference specification : EIAJ-ED-470	)2A Method5				
2	Vibration	Sweep range : 10~500Hz					
		Sweep speed : 11min/cycle					
		Amplitude : 1.5mm (10 $\sim$ 55Hz)					
		Acceleration : 200m/s <sup>2</sup> (55~500Hz)		df/f=<±0.5pp	om		
		Direction : X,Y,Z, 3directions					
		Test cycle : 10cycles					
		Reference specification : IEC 60068-2	6				
3	Shock	Acceleration : 1000m/s <sup>2</sup>					
		Direction : X,Y,Z, 6directions					
		Duration : 6ms		df/f=<±0.5pp	om		
		Test cycle : 3cycles/each directions					
		Reference specification : IEC 60068-2					
4	PCB bend	PWB : t=1.6mm					
	strength	Pressure speed : 1.0mm/s		df/f=<±0.5pp	m		
		Bend width : 1→2→3mm	No visible damage.				
		Duration : 10±1s		No leak dam	lage.		
		Reference specification : IEC 60068-2	-21 Ue1				
5	Adherence nature	PWB : t=1.6mm					
		Direction : X,Y, 2directions		df/f=<±0.5pp	m		
		Pressure : 10N		No visible da	amage.		
		Duration : 10±1s		No leak dam	lage.		
		Reference specification : IEC 60068-2	2-21 Ue3				
6	Package strength	Pressure : 10N		df/f=<±0.5ppm			
		Duration : 10±1s		No mechanical damage.			
		Reference specification : IEC 60068-2	-77	No leak dam	mage.		
7	Gross leak	It is immersed for 3min into +125±5°C			0		
		Chlorofluorocarbon (CFCs) liquid.		No continuo	us air bubbles	5.	
		Reference specification : IEC 60068-2	<u>'-17</u>				
8	Fine leak	It shall be measured by the helium lea					
-		after pressurization for 60min by the p			0		
		of $(3.92\pm0.49) \times 10^5$ Pa in a helium gas		Less than 1.0x10 <sup>-9</sup> Pa m <sup>3</sup> /s.			
		Reference specification : IEC 60068-2					
9	Solderability	Solder bath temperature : +245±5°C		A new unifor	m coating of	solde	
0	Coldorability	Duration : $3\pm0.3s$			minimum of		
		Reference specification : IEC 60068-2	2-58		e being imme		
0	Resistance to	1) Solder iron method				1000.	
0	soldering heat	Bit size : $B(\varphi 3)$ Bit temperature : +35	50±10°C	df/f=<±0.5pp	m		
	soluening heat	Duration : 3+1/-0s /each terminal		$dV_{OUT} = <\pm 0.2$			
		It shall be measured after 2h at room t	tomporaturo	No visible da			
		humidity. Reference specification : IEC			amaye.		
			5 00000-2-20				
		2) Reflow					
		In refer to temperature profile shown in	n clause13.	df/f=<±1.0pp			
		Test cycle : 3cycles		dV <sub>OUT</sub> =<±0.2			
		It shall be measured after 2h at room t		No visible da	amage.		
		humidity. Reference specification : IEC	- 60068-2-58				
LE			mark				
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te	/06/05		Spec. No.		Rev.	Pa	
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# 11. Environmental Characteristics

Item v temperature age h temperature age midity	DescriptionTemperature : -40±3°CDuration : 1000hIt shall be measured after 2h at room temhumidity. Reference specification : IEC 60Temperature : +85±2°CDuration : 1000hIt shall be measured after 2h at room temhumidity. Reference specification : IEC 60Temperature : +85±2°CR.H. 85±5%Duration : 1000hIt shall be measured after 2h at room temhumidity. Reference specification : IEC 60Temperature : +85±2°CR.H. 85±5%Duration : 1000hIt shall be measured after 2h at room temhumidity. Reference specification : IEC 60Temperature : +85±2°CDuration : 1000hBIAS : Max value of supply voltageIt shall be measured after 2h at room temhumidity. Reference specification : IEC 60Temperature : +40±2°CR.H. 90~95%Duration : 1000hBIAS : Max value of supply voltageIt shall be measured after 2h at room temhumidity. Reference specification : IEC 60Temperature : +40±2°CR.H. 90~95%Duration : 1000hBIAS : Max value of supply voltageIt shall be measured after 2h at room temhumidity. Reference specification : IEC 60	perature, 0068-2-2 Bb 0068-2-2 Bb perature, 0068-2-3	Requirementsdf/f=< $\pm 1.0$ ppmdV <sub>OUT</sub> =< $\pm 0.2$ V <sub>P-P</sub> The electrical characterist are satisfied.df/f=< $\pm 1.0$ ppmdV <sub>OUT</sub> =< $\pm 0.2$ V <sub>P-P</sub> The electrical characterist are satisfied.df/f=< $\pm 1.0$ ppmdV <sub>OUT</sub> =< $\pm 0.2$ V <sub>P-P</sub> The electrical characterist are satisfied.df/f=< $\pm 1.0$ ppmdV <sub>OUT</sub> =< $\pm 0.2$ V <sub>P-P</sub> The electrical characterist are satisfied.df/f=< $\pm 1.0$ ppmdV <sub>OUT</sub> =< $\pm 0.2$ V <sub>P-P</sub> The electrical characterist are satisfied.df/f=< $\pm 1.0$ ppmdf/f=< $\pm 1.0$ ppm	tics
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rmal shock	Duration : 1000h BIAS : Max value of supply voltage It shall be measured after 2h at room terr		df/f=<±1.0ppm	
ermal shock	BIAS : Max value of supply voltage It shall be measured after 2h at room terr			
rmal shock	It shall be measured after 2h at room tem		$dV_{OUT} = < \pm 0.2V_{P-P}$	
rmal shock			The electrical characterist	tics
ermal shock	humidity. Reference specification : IEC 60	perature,	are satisfied.	
ermal shock		0068-2-3		
	Thermal shock : -40±3°C : 0.5h ⇔ +85±	2°C : 0.5h	df/f=<±1.0ppm	
	Test cycle : 200cycles		$dV_{OUT} = <\pm 0.2V_{P-P}$	
	Shift time : 2~3min		The electrical characterist	tics
	It shall be measured after 2h at room tem	perature,	are satisfied.	100
	humidity. Reference specification : IEC pr	ub.68-2-14.Na	are catolica.	
D	Model : Machine Model (MM)			
	V=±200V (C1=200pF, R1=0Ω)		df/f=<±1.0ppm	
	Number of times : 3times		$dV_{OUT} = < \pm 0.2V_{P-P}$	
	•			tics
			are satisfied.	
		14		
	, , , , , , , , , , , , , , , , , , ,			
	•			lics
		15	are satisfied.	
	Reference specification . EIA/JESD22-A	15		
		Model : Human Body Model (HBM) V=±1500V (C1=100pF, R1=1500Ω) Number of times : 3times Each terminal except common terminal. (Connect to test terminal)	<ul> <li>(Connect to test terminal)</li> <li>Reference specification : EIA/JESD22-A114</li> <li>Model : Human Body Model (HBM)</li> <li>V=±1500V (C1=100pF, R1=1500Ω)</li> <li>Number of times : 3times</li> <li>Each terminal except common terminal.</li> </ul>	(Connect to test terminal) Reference specification : EIA/JESD22-A114are satisfied.Model : Human Body Model (HBM) $V=\pm1500V$ (C1=100pF, R1=1500 $\Omega$ ) Number of times : 3times Each terminal except common terminal. (Connect to test terminal)df/f=<±1.0ppm dV_{OUT}=<±0.2V_{P-P} The electrical characterist are satisfied.

12. Flatness of <sup>-</sup> When the com	<b>Ferminal</b> ponent is placed on the flat surface, the gap from the	connecting terminal shall nc	ot exceed 0.05	mm.
		Gap : 0.05mm max.		
13. Reflow Profi	le			
Temperature	+260°C +220°C +160~+180°C 1			
	Time			
	1         Preheat         +160~+180°C           2         Primary Heat         +220°C           3         Peak         +260°C	2 120s 60s 10s max.		
TITLE DSA321SDN TYPE	SPECIFICATION			
Date 2015/06/05	1>	Spec. No. (TV13000MAA	Rev.	Page 5/13



### 15. Packing Condition

- 15.1 Taping package
  - (1) Emboss tape format and dimensions See Fig.1
  - (2) Quantity on reel 2000pcs. max. / reel
  - (3) Taping specification
  - See Fig.2
    - No lack of a product.
  - (4) Reel specification
  - See Fig.3 (5) Taping material list
- See right table.

### 15.2 Packing

The products packed in the antistatic bag.

\*Moisture sensitivity level : IPC/JEDEC Standard J-STD-033 / Level 1

No dry pack required and baking after re-storage is unnecessary.

### 15.3 Packing box

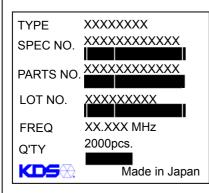
Max 10 reels/packing box. However, in the case of less than 10 reels, It is contained by any boxes. The space in a box is fill up with a cushion.

### 15.4 Label detail

A Lot label is put on a reel and a shipping label and Pb-Free label is put on a packing box.

Lot label		Shipping label		Pb-free Label
TYPE SPEC NO.	(Model Name) (Spec. Number)	ITEM SPEC	(Model Name) (Spec. Number)	
PARTS NO.	(Lot Number)	DELIVERY DATE Q'TY	(Delivery Date) (Quantity)	(HD)
FREQ. Q'TY KDS	(Nominal Frequency) (Quantity) DAISHINKU CORP.	NOTES DAISHINKU CORF	(User's Parts Number) p.	Pb-free

### Lot label (Example)



### Formation of a lot number

e.g. AH5101001			
<u> </u>	<u>_H_</u>	5101	001
Manufacturing site code	Product code	year/ month/ day	Serial No.

Taping material List

Emboss : PS (Conductivity)

Reel : PS (Conductivity)

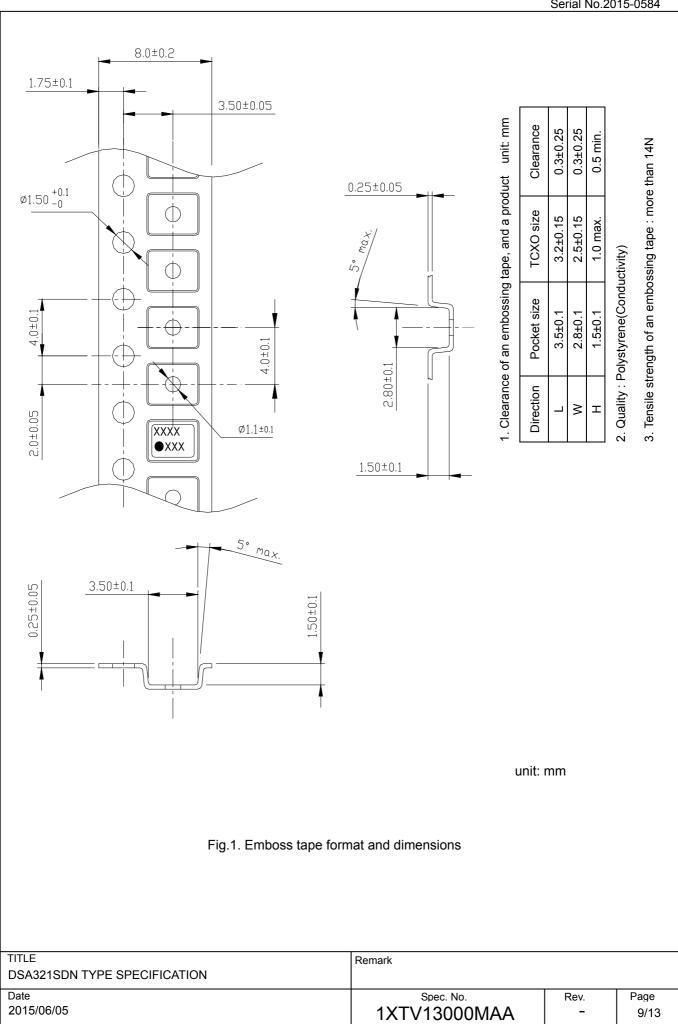
Cover Tape : PET + Olefin Resin (Conductivity)

The notation method of a manufacture year, month, and day. (4digits alphanumeric character)

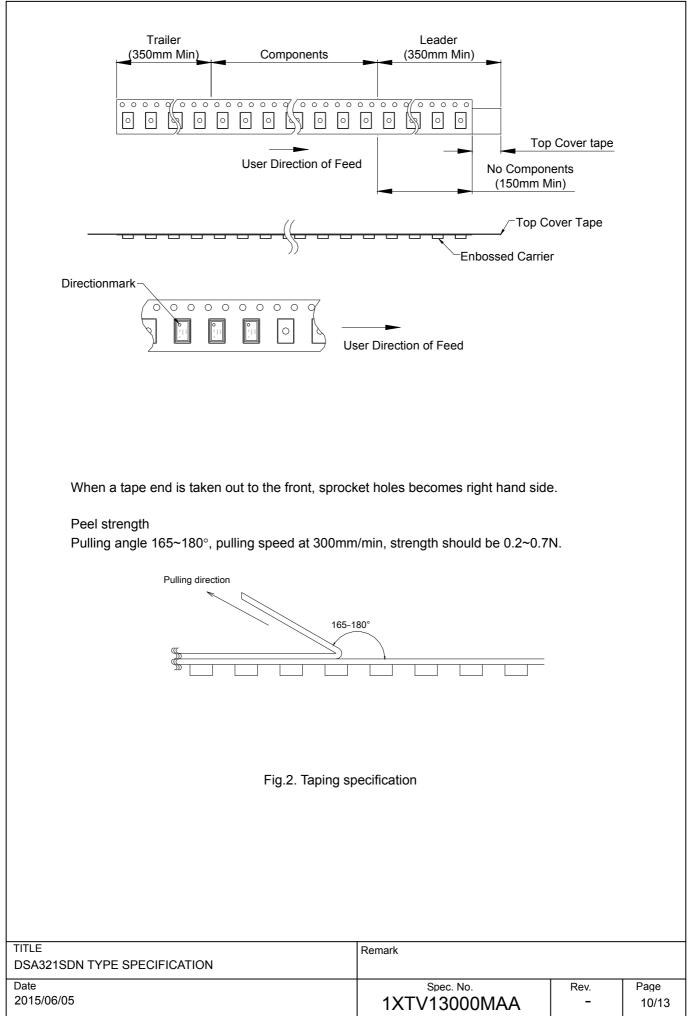
<u>YMDD</u> (4digits)				ts) e	.g.) 20	)1 <u>5</u> /0 <u>1</u>	/ <u>01</u> →	<u>5101</u>				
<u>Y</u> Year				1	digit (l	_ast di	git of <b>\</b>	/ear)				
<u>M</u> Month				า 1	digit a	Iphanu	umeric	symbo	ol			
<u>DD</u> Day				2	digits	numer	ical ch	aracte	ers of d	lay		
Month	Jan.	Feb.	Mar.	Apr.	May.	Jun.	Jul.	Aug.	Sep.	Oct.	Nov.	Dec.
Symbol	1	2	3	4	5	6	7	8	9	0	Ν	D

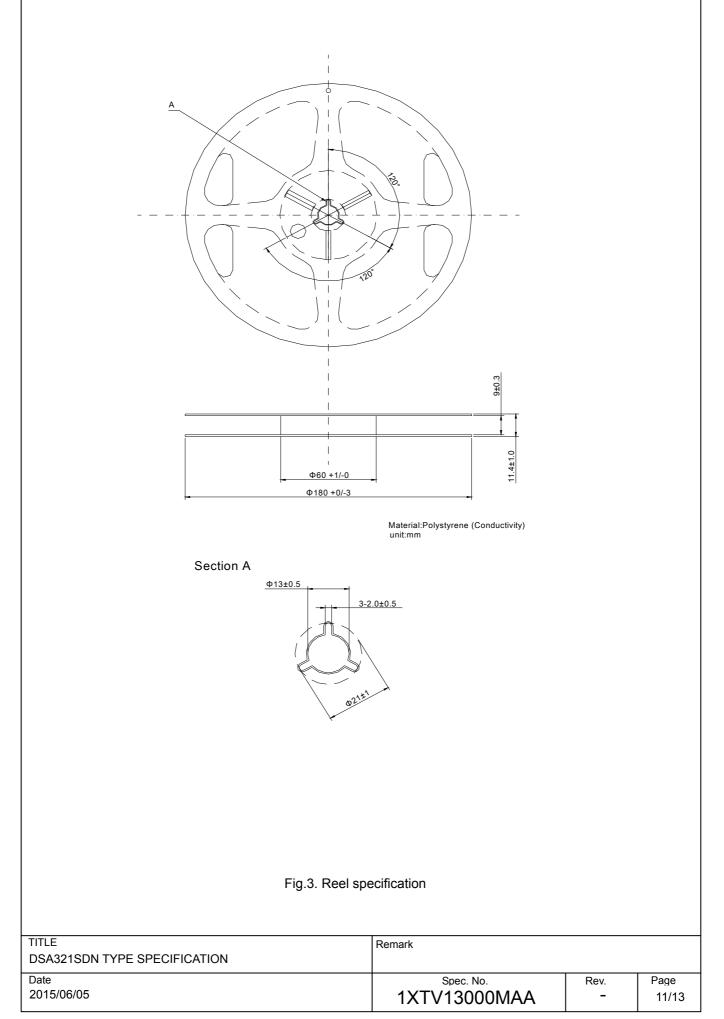
TITLE	Remark		
DSA321SDN TYPE SPECIFICATION			
Date	Spec. No.	Rev.	Page
2015/06/05	1XTV13000MAA	-	7/13

Lot Label			
	ir Cushion		
	Pb-free Label		7
The product is packed up with the method which d	oes not break in the handling by a shipping	g agent.	
TLE SA321SDN TYPE SPECIFICATION	Remark		
ate 015/06/05	Spec. No. 1XTV13000MAA	Rev. –	Page 8/13



DM-Z0002: Style-010 Ver.1





### 16. Notes on mounting and handling

### 16.1 Storage environment

- (1) The temperature and humidity of a storage place, Please give +5~+40°C and 40~85% as a standard.
- (2) Please use this product within one year from the packing label date of issue.
- (3) Please avoid the place which generates corrosive gas, and the place with much dirt.
- (4) Please keep it in a place with little temperature change.
- Dew condensation arises owing to a rapid temperature change and solderability becomes bad.
- 16.2 Be cautions to static electricity and high voltage.
- 16.3 This product has sufficient durability to fall and vibration. However, conditions may change to the fall after mounting to a PWB, and vibration. When you should drop on a floor the PWB which mounted the product or too much shock is added. Please use after a performance check.
- 16.4 Please check that the curvature of the substrate at the time of substrate cutting does not affect product. Moreover, especially when a product is near the position of a PWB guide pin, and the position of PWB break, be careful.
- 16.5 The part concerned does not correspond to washing.

16.6 Please repair at +260°C in 10s with hot air or +350°C in 5s with solder Iron.

### 17. Mandatory control

17.1 Ozone-depleting substance

It regulates by the U.S. air purifying method (November, 1990 establishment). ODS of CLASS1 and CLASS2 is not contained or used.

#### 17.2 PBDE, PBBs

PBDE, PBBs are not contained into all the material currently used for this product.

#### 17.3 RoHS

Following material restricted by RoHS (2011/65/EU) is not included or used. Lead, mercury, cadmium, hexavalent, chromium, PBB and PBDE.

17.4 Law Concerning Examination and Regulation of Manufacture, etc. of Chemical Substances

All the material currently used for this product is based on "Law Concerning Examination and Regulation of Manufacture, etc. of Chemical Substances". It is a registered material.

#### 17.5 Lead

Leads, such as solder, are not used for this product. (Lead Free)

#### 17.6 About the existence of silver and mercury use

The silver of very small quantity is contained in the conductive adhesives used for adhesion of Blank. Moreover, mercury is used. It does not get down.

#### 18. The country of origin / factory name / address

Country of origin:	Japan
Factory name:	DAISHINKU Corp. Tottori Production Div.
Address:	7-3-21 Wakabadai minami, Tottori 689-1112

TITLE	Remark		
DSA321SDN TYPE SPECIFICATION			
Date	Spec. No.	Rev.	Page
2015/06/05	1XTV13000MAA	-	12/13

### 2015-0584 REVERSION RECORD

Rev. No.	Date	Reason	Contents	Approved	Checked	Drawn
-	2015/06/05	-	Initial Release	A.Hishikawa	H.Takase	S.Fujihira